



Sheet 1 of 1

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)	ATTY. DOCKET NO. H1938	SERIAL NO. 10/601,401
	APPLICANT Zoran Krivokapic	
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U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
<i>SDI</i>	2001/0036731	11/01/01	Muller, et al.			
<i>SDI</i>	2002/0003256	01/10/02	Maegawa			
<i>SDI</i>	2003/0025126	02/06/03	Hsu			
<i>SDI</i>	2003/0057486	03/27/03	Gambino, et al.			

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION
<i>SDI</i>	2004/044992	05/27/04	WO			

OTHER DOCUMENTS (Including Author, Title, Date Pertinent Pages, Etc.)

<i>SDI</i>	K. Ota, K. Sugihara, H. Sayama, T. Uchida, H. Oda, T. Eimori, H. Morimoto and Y. Inoue, Novel Locally Strained Channel Technique for High Performance 55nm CMOS, IEDM Technical Digest, December 8, 2002, pp. 27-30.
<i>SDI</i>	A. Shimizu, K. Hachimine, N. Ohki, H. Ohta, M. Koguchi, Y. Nonaka, H. Sato, and F. Ootsuka, Local Mechanical-Stress Control (LMC): A New Technique for CMOS-Performance Enhancement, IEDM Technical Digest, December 2, 2001, pp. 433-436.

EXAMINER

*Stavetta Lopez*DATE
CONSIDERED*4/16/05*

EXAMINER: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.